PNP/PNP resistor-equipped transistors; R1 = 10 kΩ, R2 = 10 kΩ

Rev. 3 — 30 November 2011

Product data sheet

Product profile 1.

1.1 General description

PNP/PNP Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

| Type number | Package | | | NPN/NPN | Package |
|-------------|---------|-------|------------|------------|---------------------------|
| | NXP | JEITA | complement | complement | configuration |
| PEMB11 | SOT666 | - | PEMD3 | PEMH11 | ultra small and flat lead |
| PUMB11 | SOT363 | SC-88 | PUMD3 | PUMH11 | very small |

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|---------------------------|------------|-----|-----|------|------|
| Per transis | stor | | | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | -50 | V |
| I _O | output current | | - | - | -100 | mA |
| R1 | bias resistor 1 (input) | | 7 | 10 | 13 | kΩ |
| R2/R1 | bias resistor ratio | | 0.8 | 1.0 | 1.2 | |



006aaa212

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

Pinning information 2.

| Table 3. | Pinning | | |
|----------|------------------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | GND (emitter) TR1 | | |
| 2 | input (base) TR1 | 6 5 4 | |
| 3 | output (collector) TR2 | | |
| 4 | GND (emitter) TR2 | | |
| 5 | input (base) TR2 | | |
| 6 | output (collector) TR1 | 001aab555 | |

Ordering information 3.

Table 4. **Ordering information**

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| PEMB11 | - | plastic surface-mounted package; 6 leads | SOT666 |
| PUMB11 | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |

Marking 4.

| Marking code ^[1] |
|-----------------------------|
| B1 |
| B*1 |
| |

[1] * = placeholder for manufacturing site code.

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

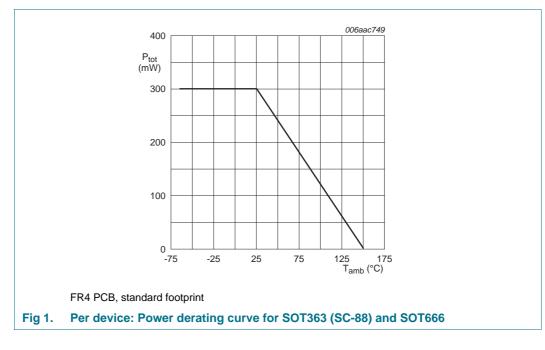
5. Limiting values

| Table 6. In accordar | Limiting values | ım Rating System (IE | C 60134). | | |
|--------------------------------|---------------------------|------------------------------|------------|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| Per transis | stor | | | | |
| V _{CBO} | collector-base voltage | open emitter | - | -50 | V |
| V _{CEO} | collector-emitter voltage | open base | - | -50 | V |
| V _{EBO} | emitter-base voltage | open collector | - | -10 | V |
| VI | input voltage | | | | |
| | positive | | - | +10 | V |
| | negative | | - | -40 | V |
| lo | output current | | - | -100 | mA |
| I _{CM} | peak collector current | | - | -100 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | [1] | | |
| | PEMB11 (SOT666) | | [2] _ | 200 | mW |
| | PUMB11 (SOT363) | | - | 200 | mW |
| Per device | ; | | | | |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | <u>[1]</u> | | |
| | PEMB11 (SOT666) | | [2] _ | 300 | mW |
| | PUMB11 (SOT363) | | - | 300 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



6. Thermal characteristics

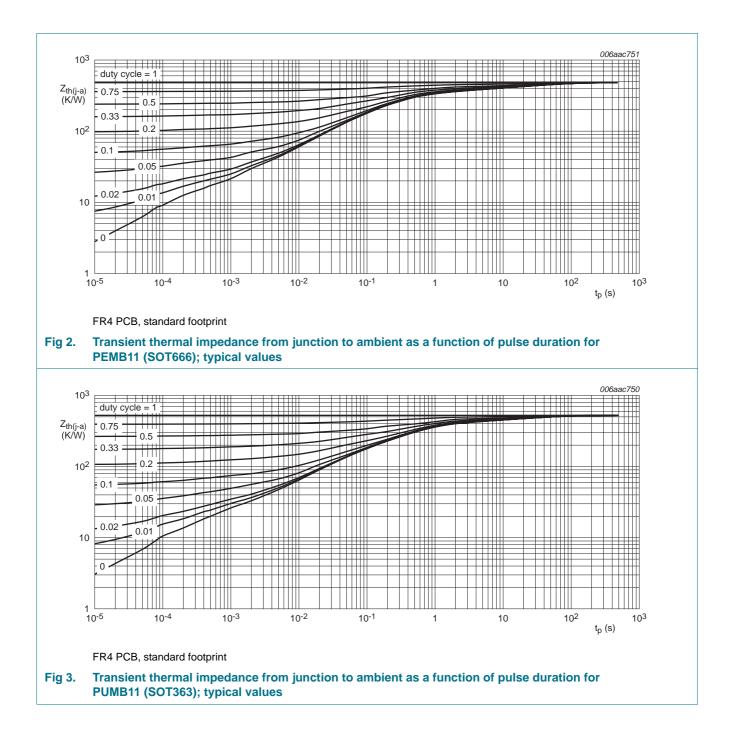
| Table 7. | Thermal characteristic | s | | | | |
|----------------------|---|-------------|------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Per trans | istor | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1]</u> | | | |
| | PEMB11 (SOT666) | | [2] _ | - | 625 | K/W |
| | PUMB11 (SOT363) | | - | - | 625 | K/W |
| Per devic | e | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1]</u> | | | |
| | PEMB11 (SOT666) | | [2] _ | - | 417 | K/W |
| | PUMB11 (SOT363) | | - | - | 417 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

PEMB11; PUMB11

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

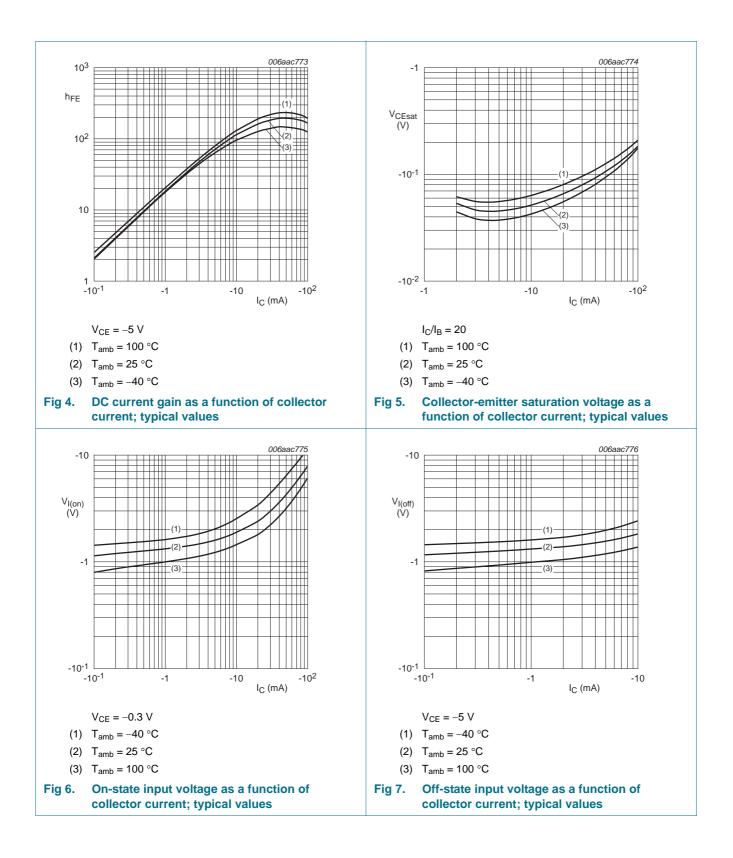
7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------|---|--|------------|------|------|------|------|
| Per trans | istor | | | | | | |
| I _{CBO} | collector-base cut-off current | $V_{CB} = -50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$ | | - | - | -100 | nA |
| I _{CEO} | collector-emitter | $V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$ | | - | - | -1 | μΑ |
| | cut-off current | $V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0 \text{ A};$ T _j = 150 °C | | - | - | -5 | μA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | | - | - | -400 | μΑ |
| h _{FE} | DC current gain | V_{CE} = -5 V; I _C = -5 mA | | -30 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}$ | | - | - | -150 | mV |
| V _{I(off)} | off-state input voltage | $V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \mu\text{A}$ | | - | -1.1 | -0.8 | V |
| V _{I(on)} | on-state input voltage | V_{CE} = –0.3 V; I_{C} = –10 mA | | -2.5 | -1.8 | - | V |
| R1 | bias resistor 1 (input) | | | 7 | 10 | 13 | kΩ |
| R2/R1 | bias resistor ratio | | | 0.8 | 1.0 | 1.2 | |
| C _c | collector capacitance | $\label{eq:VCB} \begin{split} V_{CB} = -10 \ V; \ I_E = i_e = 0 \ A; \\ f = 1 \ MHz \end{split}$ | | - | - | 3 | pF |
| f _T | transition frequency | $V_{CB} = -5 \text{ V}; I_C = -10 \text{ mA};$ f = 100 MHz | <u>[1]</u> | - | 180 | - | MHz |

[1] Characteristics of built-in transistor.

PEMB11; PUMB11

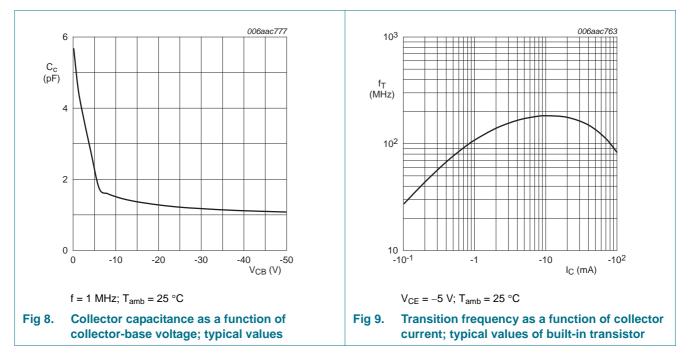
PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



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PEMB11; PUMB11

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

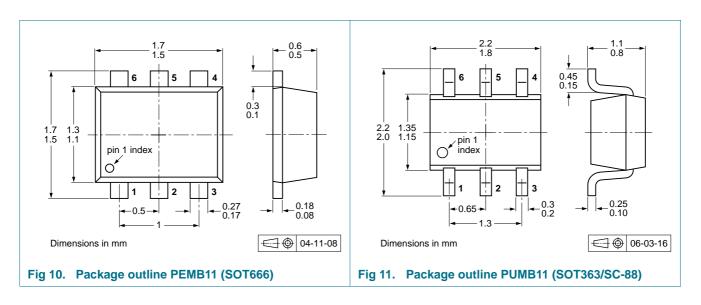


8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

10. Packing information

Table 9. Packing methods

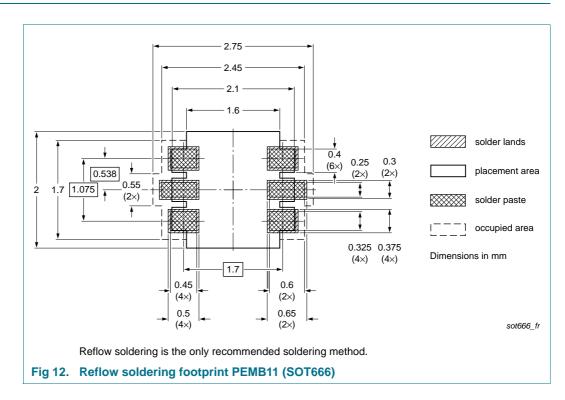
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | ckage Description | | Packing quantity | | | |
|---------------|---------|------------------------------------|-----|------------------|------|------|-------|
| | | | | 3000 | 4000 | 8000 | 10000 |
| PEMB11 SOT666 | | 2 mm pitch, 8 mm tape and reel | | - | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | • | - | -115 | - | - |
| PUMB11 SOT363 | | 4 mm pitch, 8 mm tape and reel; T1 | [2] | -115 | - | - | -135 |
| | | 4 mm pitch, 8 mm tape and reel; T2 | [3] | -125 | - | - | -165 |

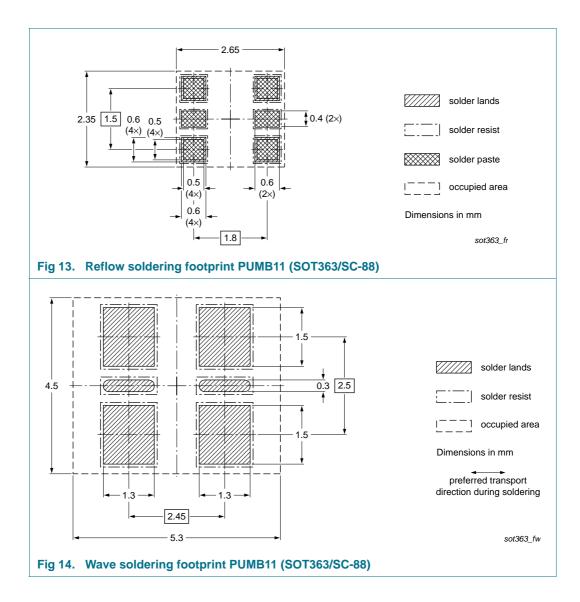
[1] For further information and the availability of packing methods, see Section 14.

- [2] T1: normal taping
- [3] T2: reverse taping

11. Soldering



PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

12. Revision history

| Table 10. Revision history | | | | | | |
|----------------------------|--|---|--------------------|---------------------------|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
| PEMB11_PUMB11 v.3 | 20111130 | Product data sheet | - | PEMB11_PUMB11 v.2 | | |
| Modifications: | | of this document has been f NXP Semiconductors. | redesigned to corr | ply with the new identity | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | <u>Section 1 "Product profile"</u>: updated | | | | | |
| | <u>Section 4 "Marking"</u>: updated | | | | | |
| | <u>Table 7 "Thermal characteristics"</u>: updated according to the latest measurements | | | | | |
| | <u>Table 8 "Characteristics</u>": I_{CEO} updated according to the latest measurements, V_{i(on)} and V_{i(off)} changed respectively to V_{I(on)} and V_{I(off)}, f_T added | | | | | |
| | • Figure 1 to 9: added | | | | | |
| | <u>Section 8 "Test information"</u> : added | | | | | |
| | Figure 11 and 10: replaced by minimized package outline drawings | | | | | |
| | Section 10 "Packing information": added | | | | | |
| | <u>Section 11 "Soldering"</u> : added | | | | | |
| | Section 13 " | Legal information": update | d | | | |
| PEMB11_PUMB11 v.2 | 20031003 | Product data sheet | - | PEMB11 v.1 PUMB11 v.1 | | |
| PEMB11 v.1 | 20010913 | Preliminary specification | - | - | | |
| PUMB11 v.1 | 20000808 | Product specification | - | - | | |

PEMB11_PUMB11

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

13. Legal information

13.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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